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# 2SK2212

## Silicon N Channel MOS FET

REJ03G1003-0200

(Previous: ADE-208-1351)

Rev.2.00 Sep 07, 2005

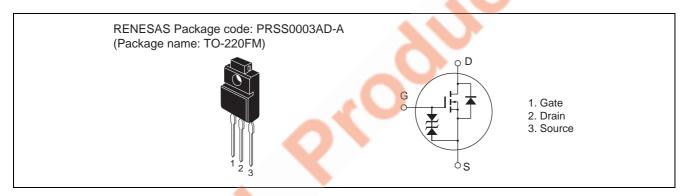
### **Application**

High speed power switching

#### **Features**

- Low on-resistance
- High speed switching
- Low drive current
- No secondary breakdown
- Suitable for switching regulator, DC-DC converter, motor control

#### **Outline**



## **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

| Item                                      | Symbol                   | Ratings     | Unit |
|---|--------------------------|-------------|------|
| Drain to source voltage                   | V <sub>DSS</sub>         | 200         | V    |
| Gate to source voltage                    | $V_{GSS}$                | ±20         | V    |
| Drain current                             | I <sub>D</sub>           | 10          | А    |
| Drain peak current                        | I <sub>D(pulse)</sub> *1 | 40          | А    |
| Body to drain diode reverse drain current | I <sub>DR</sub>          | 10          | А    |
| Channel dissipation                       | Pch*2                    | 30          | W    |
| Channel temperature                       | Tch                      | 150         | °C   |
| Storage temperature                       | Tstg                     | -55 to +150 | °C   |

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1 %

2. Value at Tc = 25°C

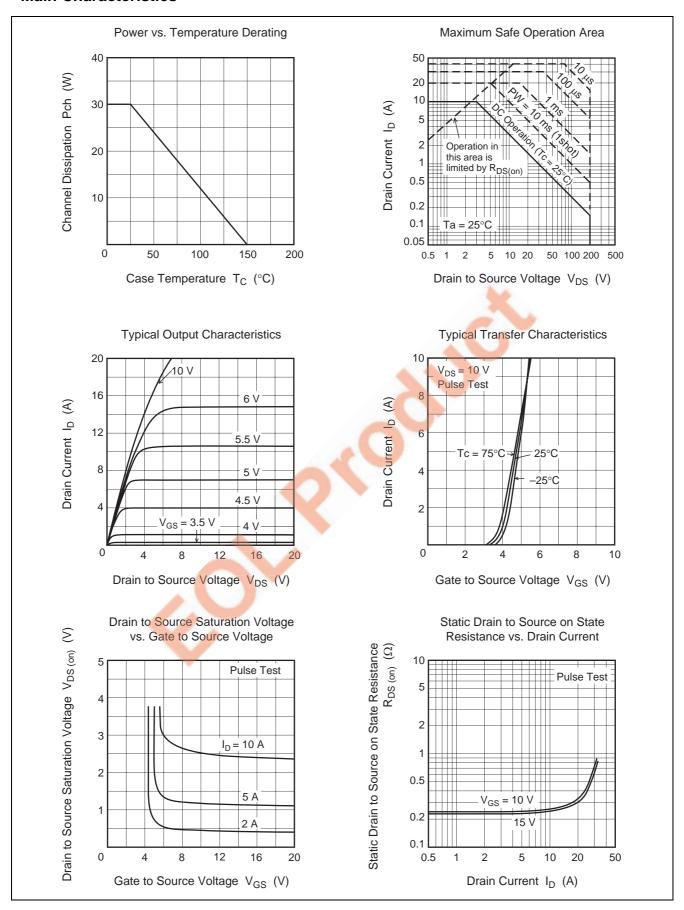
### **Electrical Characteristics**

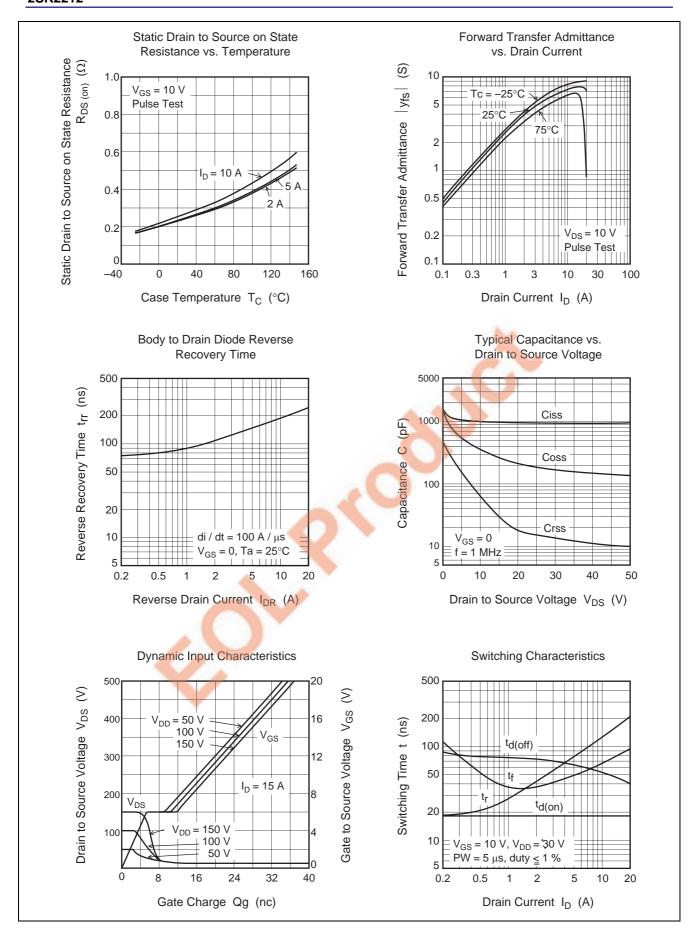
 $(Ta = 25^{\circ}C)$ 

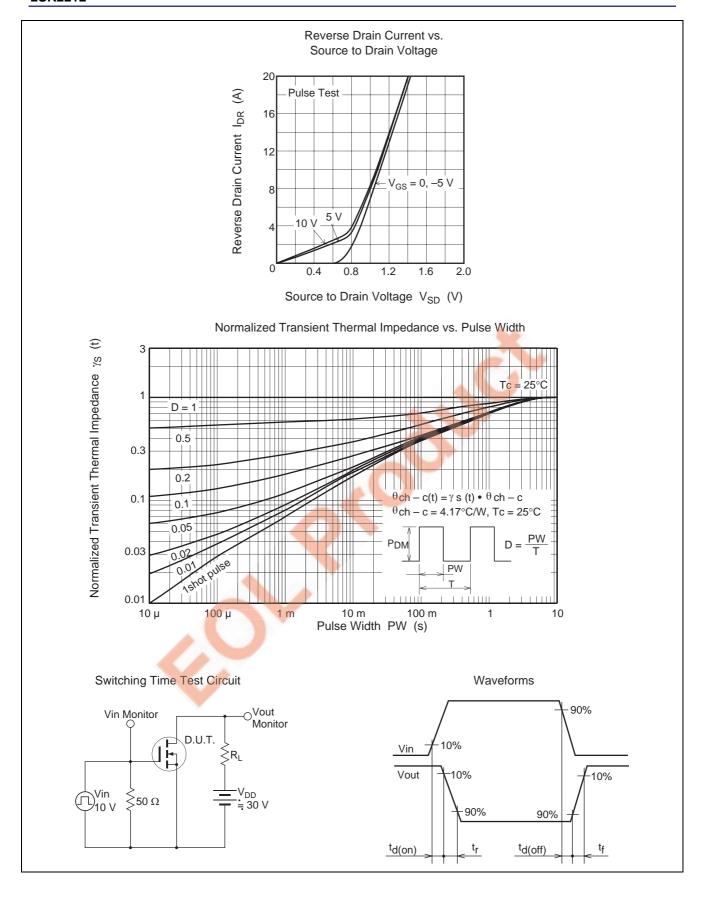
| Item                                | Symbol              | Min          | Тур  | Max | Unit | Test conditions                                 |
|-------------------------------------|---------------------|--------------|------|-----|------|---|
| Drain to source breakdown voltage   | $V_{(BR)DSS}$       | 200          | _    | _   | V    | $I_D = 10 \text{ mA}, V_{GS} = 0$               |
| Gate to source breakdown voltage    | $V_{(BR)GSS}$       | ±20          | _    | _/  | V    | $I_G = \pm 100 \mu\text{A},  V_{DS} = 0$        |
| Gate to source leak current         | I <sub>GSS</sub>    | _            | _    | ±10 | μΑ   | $V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$         |
| Zero gate voltage drain current     | I <sub>DSS</sub>    | _            | _    | 250 | μА   | V <sub>DS</sub> = 160 V, V <sub>GS</sub> = 0    |
| Gate to source cutoff voltage       | $V_{GS(off)}$       | 2.0          | _/   | 4.0 | V    | $I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}$     |
| Static drain to source on state     | R <sub>DS(on)</sub> | _            | 0.24 | 0.3 | Ω    | $I_D = 5 \text{ A}, V_{GS} = 10 \text{ V}^{*1}$ |
| resistance                          |                     |              |      |     |      |   |
| Forward transfer admittance         | y <sub>fs</sub>     | 3.5          | 6    |     | S    | $I_D = 5 \text{ A}, V_{DS} = 10 \text{ V}^{*1}$ |
| Input capacitance                   | Ciss                | _            | 1000 |     | pF   | $V_{DS} = 10 \text{ V}, V_{GS} = 0,$            |
| Output capacitance                  | Coss                | F3           | 360  | -   | pF   | f = 1 MHz                                       |
| Reverse transfer capacitance        | Crss                |              | 65   | _   | pF   |   |
| Turn-on delay time                  | t <sub>d(on)</sub>  | -            | 18   | _   | ns   | $I_D = 5 \text{ A}, V_{GS} = 10 \text{ V},$     |
| Rise time                           | tη                  | _            | 80   | _   | ns   | $R_L = 6 \Omega$                                |
| Turn-off delay time                 | t <sub>d(off)</sub> | <u></u>      | 65   | _   | ns   |   |
| Fall time                           | t <sub>f</sub>      | <del>-</del> | 50   | _   | ns   |   |
| Body to drain diode forward voltage | V <sub>DF</sub>     | _            | 1.1  | _   | V    | I <sub>F</sub> = 10 A, V <sub>GS</sub> = 0      |
| Body to drain diode reverse         | t <sub>rr</sub>     | _            | 190  | _   | ns   | $I_F = 10 \text{ A}, V_{GS} = 0,$               |
| recovery time                       |                     |              |      |     |      | $di_F / dt = 100 A / \mu s$                     |

Note: 1. Pulse Test

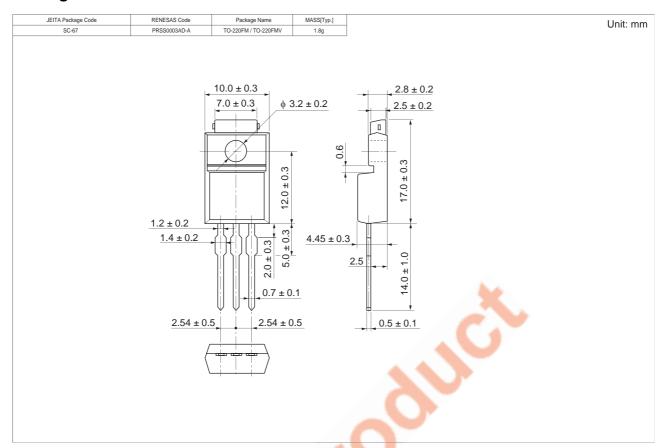
#### **Main Characteristics**







### **Package Dimensions**



### **Ordering Information**

| Part Name | Quantity | Shipping Container |
|-----------|----------|--------------------|
| 2SK2212-E | 500 pcs  | Box (Sack)         |

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Renesas Technology Europe Limited
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